



DMT15H017LPS

PowerDI5060-8

#### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> Max T <sub>C</sub> = +25°C
4501/	17.5mΩ @ V <sub>GS</sub> = 10V	58A
150V	25.5mΩ @ V <sub>GS</sub> = 4.5V	48A

## Description

This new generation N-Channel Enhancement Mode MOSFET is designed to minimize  $R_{DS(ON)}$ , yet maintain superior switching performance. This device is ideal for use in notebook battery power management and load switch.

PowerDI5060-8

## **Applications**

- Synchronous Rectification
- Power Switching
- Class D Audio Amplifier

#### Features

 100% Unclamped Inductive Switching (UIS) Test in Production – Ensures More Reliable and Robust End Application

**150V N-CHANNEL ENHANCEMENT MODE MOSFET** 

- Thermally Efficient Package-Cooler Running Applications
- High Conversion Efficiency
- Low R<sub>DS(ON)</sub> Minimizes On-State Losses
- Low Input Capacitance
- Fast Switching Speed
- <1.1mm Package Profile Ideal for Thin Applications (PowerDI<sup>®</sup>)
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q101, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative.
- <u>https://www.diodes.com/quality/product-definitions/</u>

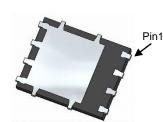
## **Mechanical Data**

- Case: PowerDI5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Terminal Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 📵
- Weight: 0.097 grams (Approximate)

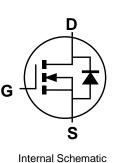


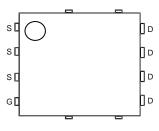
Top View

Notes:



Bottom View





Top View Pin Configuration

### Ordering Information (Note 4)

Part Number	Case	Packaging
DMT15H017LPS-13	PowerDI5060-8	2,500 / Tape & Reel

1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

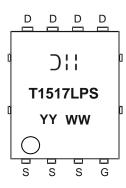
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free

 Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.</li>

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



## **Marking Information**



) | | = Manufacturer's Marking T1517LPS = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 19 = 2019) WW = Week Code (01 to 53)

## Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	V <sub>DSS</sub>	150	V		
Gate-Source Voltage	V <sub>GSS</sub>	±20	V		
	Steady	T <sub>A</sub> = +25°C	- I <sub>D</sub> -	9.4	A
Continuous Drain Current V <sub>GS</sub> = 10V (Note 6)	State	T <sub>A</sub> = +70°C		7.5	
Continuous Drain Current V <sub>GS</sub> = 10V (Note 7)	Steady	T <sub>C</sub> = +25°C	- I <sub>D</sub>	58	А
	State	T <sub>C</sub> = +70°C		46	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	•	I <sub>DM</sub>	230	А	
Maximum Continuous Body Diode Forward Current	Is	74	А		
Pulsed Body Diode Current (10µs Pulse, Duty Cycle = 1	I <sub>SM</sub>	230	А		
Avalanche Current (Note 8), L = 3mH			I <sub>AS</sub>	14.5	А
Avalanche Energy (Note 8), L = 3mH			E <sub>AS</sub>	315.4	mJ

## **Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T <sub>A</sub> = +25°C	PD	1.3	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{ heta JA}$	99	°C/W
Total Power Dissipation (Note 6)	T <sub>A</sub> = +25°C	PD	2.3	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{ extsf{ heta}JA}$	53	°C/W
Total Power Dissipation (Note 7)	T <sub>C</sub> = +25°C	PD	89	W
Thermal Resistance, Junction to Case (Note 7)		$R_{\theta JC}$	1.4	°C/W
Operating and Storage Temperature Range		T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C

Notes: 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.

6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.

7. Thermal resistance from junction to soldering point (on the exposed drain pad).

8.  $I_{AS}$  and  $E_{AS}$  ratings are based on low frequency and duty cycles to keep  $T_J = +25^{\circ}C$ .



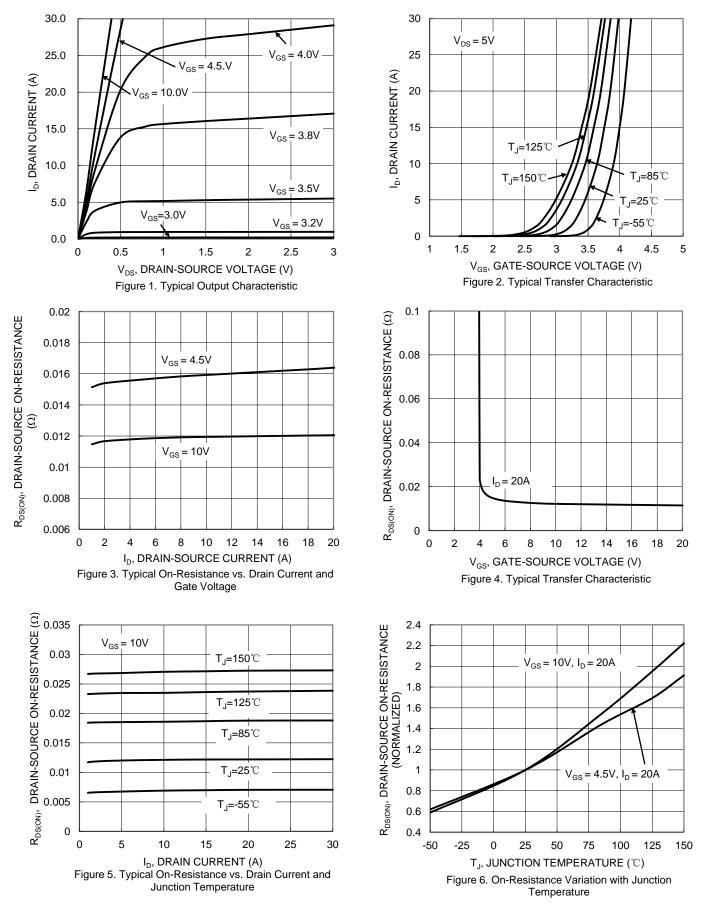
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)						•	
Drain-Source Breakdown Voltage	<b>BV</b> <sub>DSS</sub>	150	_	_	V	$V_{GS} = 0V, I_{D} = 10mA$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	1	μA	$V_{DS} = 120V, V_{GS} = 0V$	
Gate-Source Leakage	Igss		_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1.3	—	2.6	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
Static Drain-Source On-Resistance	<b>B</b>	_	14	17.5	mΩ	$V_{GS} = 10V, I_D = 20A$	
	R <sub>DS(ON)</sub>		18	25.5	11152	$V_{GS} = 4.5V, I_D = 20A$	
Diode Forward Voltage	V <sub>SD</sub>		0.8	1.2	V	$V_{GS} = 0V, I_{S} = 20A$	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	C <sub>iss</sub>		3369	—			
Output Capacitance	Coss		211	_	pF	$V_{DS} = 75V, V_{GS} = 0V$ f = 1MHz	
Reverse Transfer Capacitance	Crss		6.7	_			
Gate Resistance	Rg	_	1.9	_	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Total Gate Charge	Qg	_	50	_			
Gate-Source Charge	Q <sub>gs</sub>	_	12.8	_	nC	$V_{DD} = 75V, I_D = 20A,$ $V_{GS} = 10V$	
Gate-Drain Charge	Q <sub>qd</sub>	_	9.4	_		$v_{GS} = 10v$	
Turn-On Delay Time	t <sub>D(ON)</sub>		10.5	_			
Turn-On Rise Time	t <sub>R</sub>	_	16.3	_		$V_{DD} = 75V, V_{GS} = 10V,$	
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	44.6	—	ns	$I_D = 20A, R_g = 6\Omega$	
Turn-Off Fall Time	tF		17.7	—		-	
Reverse Recovery Time	t <sub>RR</sub>		72	—	ns		
Reverse Recovery Charge	Q <sub>RR</sub>		215	_	nC	$I_F = 20A, di/dt = 100A/\mu s$	

Notes:9. Short duration pulse test used to minimize self-heating effect.10. Guaranteed by design. Not subject to product testing.

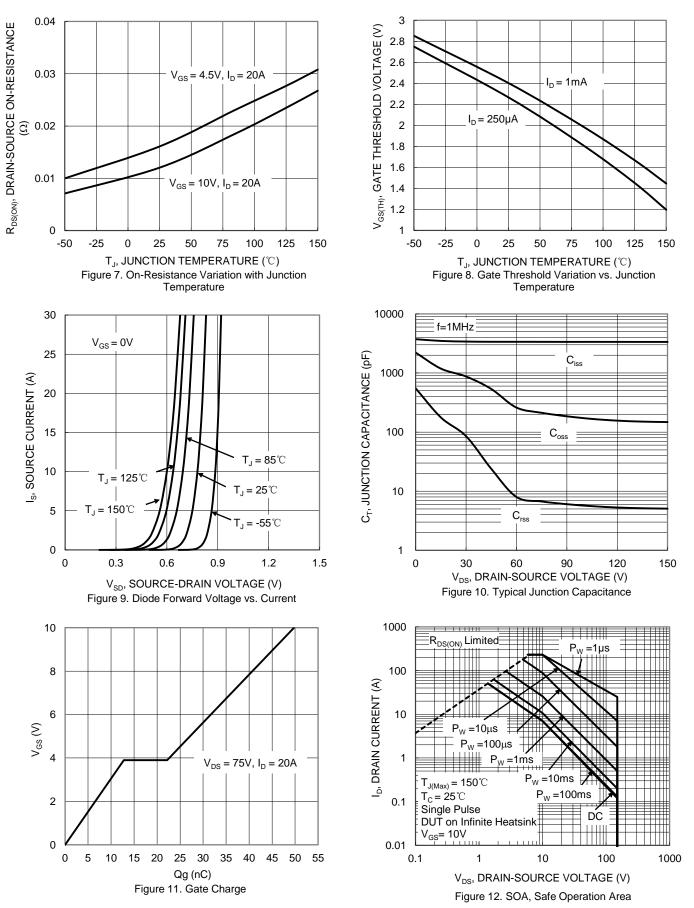


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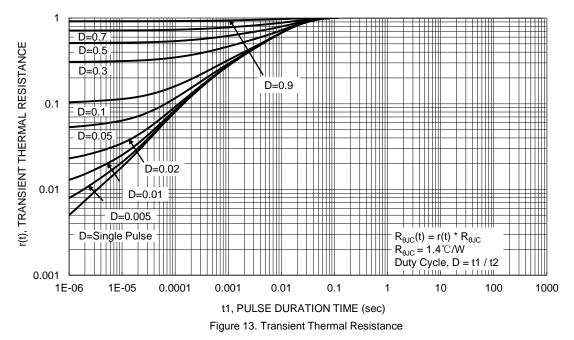




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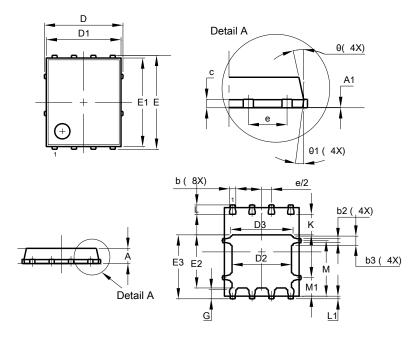




## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8

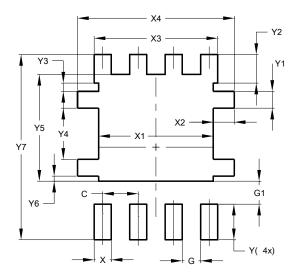


PowerDI5060-8						
			Тур			
A	0.90	1.10	1.00			
A1	0.00	0.05	-			
b	0.33	0.51	0.41			
b2	0.200	0.350	0.273			
b3	0.40	0.80	0.60			
С	0.230	0.330	0.277			
D	ļ	5.15 BSC				
D1	4.70	5.10	4.90			
D2	3.70	4.10	3.90			
D3	3.90	4.30	4.10			
E	6.15 BSC					
E1	5.60	6.00	5.80			
E2	3.28	3.68	3.48			
E3	3.99	4.39	4.19			
е	1.27 BSC					
G	0.51	0.71	0.61			
K	0.51	-	-			
L	0.51	0.71	0.61			
L1	0.100	0.200	0.175			
М	3.235	4.035	3.635			
M1	1.00	1.40	1.21			
Θ	10°	12°	11°			
Θ1	6°	8°	7°			
All	All Dimensions in mm					

## Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	0.755
X3	4.420
X4	5.610
Y	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610



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